

**Features**

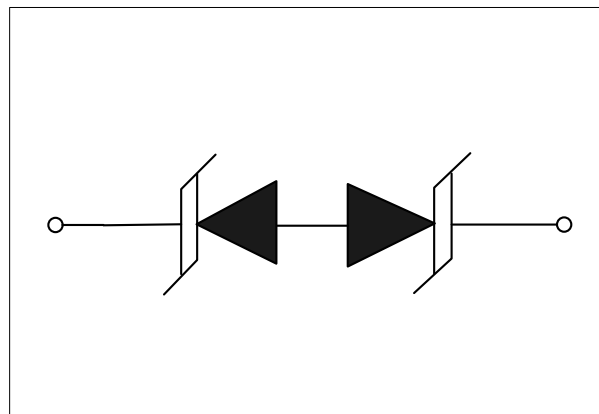
- Small Body Outline Dimensions: 0.60 mm x 0.30 mm
- 100 Watts Peak Pulse Power per Line ( $t_p=8/20\mu s$ )
- Bidirectional ESD Protection of one line
- Low Clamping Voltage
- Working Voltage: 3.3 V
- Low Leakage Current

**IEC COMPATIBILITY (EN61000-4)**

- IEC 61000-4-2 (ESD)  $\pm 30kV$  (air),  $\pm 30kV$  (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 7A (8/20 $\mu s$ )

**Mechanical Characteristics Applications**

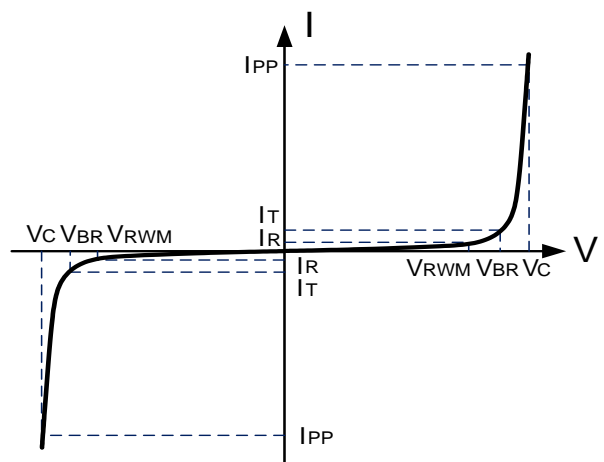
- DFN0603-2L package
- Molding compound flammability rating: UL 94V-0
- Marking: Marking Code
- Packaging: Tape and Reel per EIA 481
- RoHS Compliant
- Cellular handsets and accessories
- Portable electronics
- Communication systems
- Computers and peripherals

**Schematic & PIN Configuration**

Absolute Maximum Rating			
Rating	Symbol	Value	Units
Peak Pulse Power ( $t_p = 8/20\mu s$ )	PPP	100	W
Peak Pulse Current ( $t_p = 8/20\mu s$ )	I <sub>PP</sub>	7	A
Operating Temperature	T <sub>J</sub>	-55 to + 150	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

**Electrical Parameters (T=25°C)**

Symbol	Parameter
I <sub>PP</sub>	Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
V <sub>RWM</sub>	Reverse Stand-Off Voltage
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>
I <sub>T</sub>	Test Current



**Electrical Characteristics**

WE03DS-B						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>				3.3	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> =1mA	3.7		7.0	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =3.3V, T=25°C			200	nA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> =1A, t <sub>p</sub> =8/20μs		5.5	7.0	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> =7A, t <sub>p</sub> =8/20μs		8.0	10.0	V
ESD Clamping Voltage <sup>1</sup>	V <sub>C</sub>	I <sub>PP</sub> = 4A t <sub>p</sub> = 0.2/100ns		6.0		V
ESD Clamping Voltage <sup>1</sup>	V <sub>C</sub>	I <sub>PP</sub> = 16A t <sub>p</sub> = 0.2/100ns		9.5		V
Dynamic Resistance <sup>1,2</sup>	R <sub>DYN</sub>	TLP=0.2/100ns		0.3		Ω
Junction Capacitance	C <sub>J</sub>	V <sub>R</sub> = 0V, f = 1MHz		7.5	8.5	pF

**Note:** 1、 TLP Setting : t<sub>p</sub>=100ns, t<sub>r</sub>=0.2ns, I<sub>TLP</sub> and V<sub>TLP</sub> sample window:t<sub>1</sub>=70ns to t<sub>2</sub>=90ns.

2、 Dynamic resistance calculated from I<sub>PP</sub>=4A to I<sub>PP</sub>=16A using “Best Fit”

Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

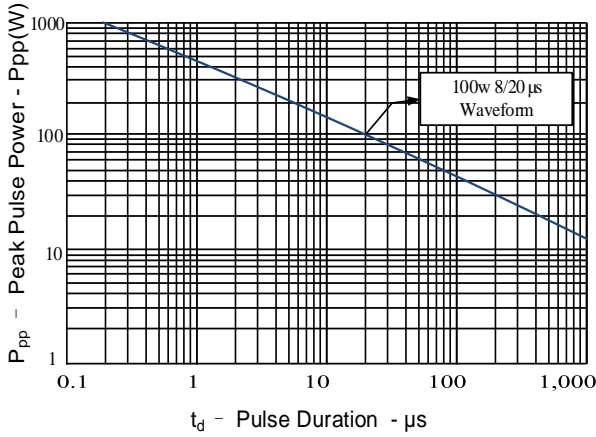


Figure 2: Power Derating Curve

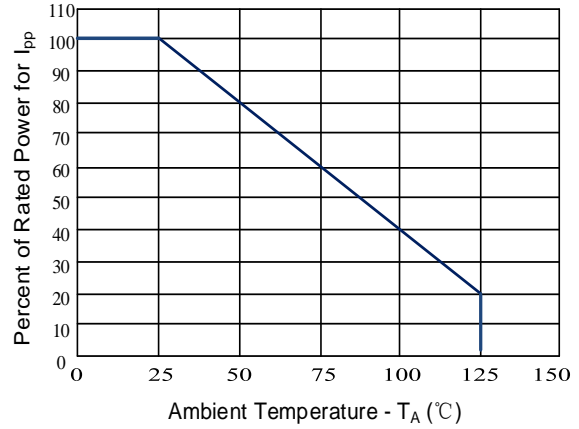


Figure 3: Clamping Voltage vs. Peak Pulse Current

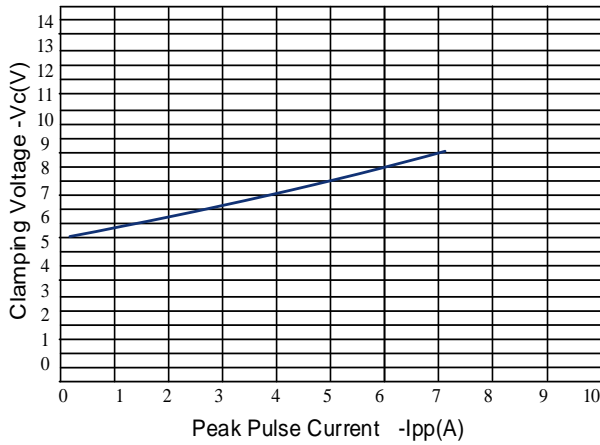


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

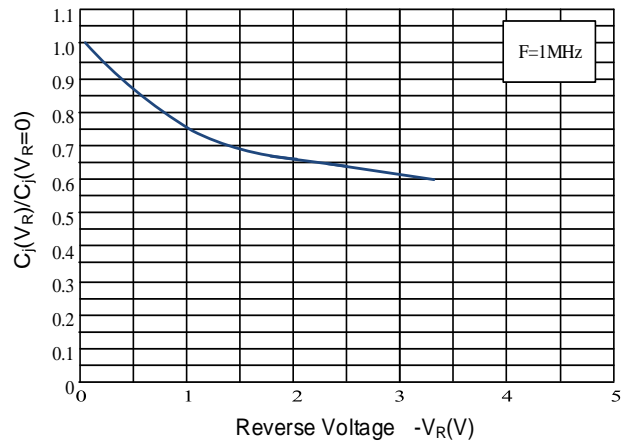


Figure 5: TLP Positive I-V Curve

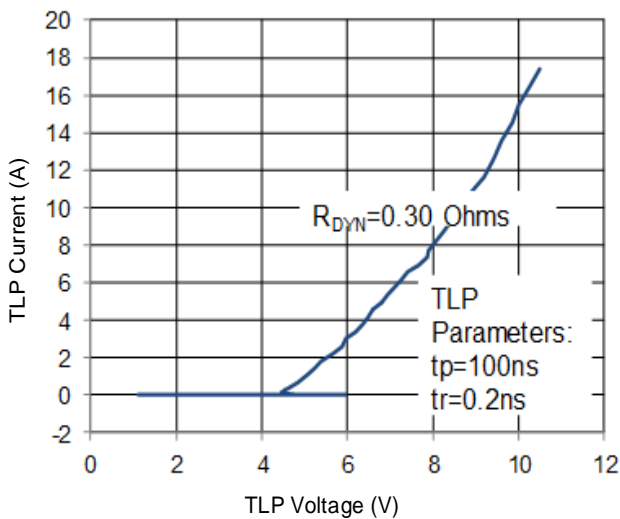
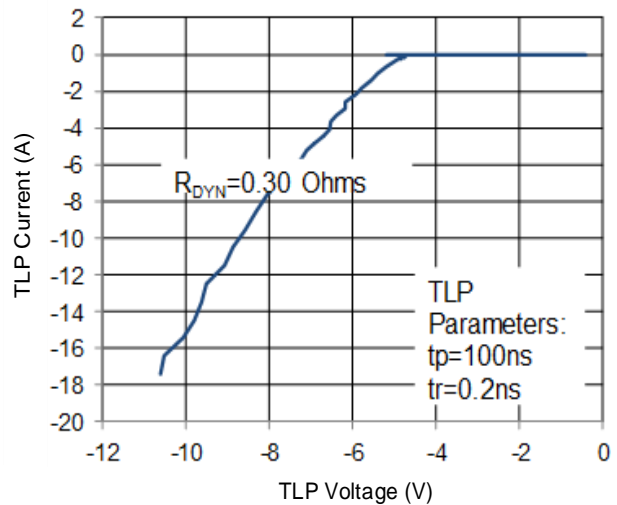
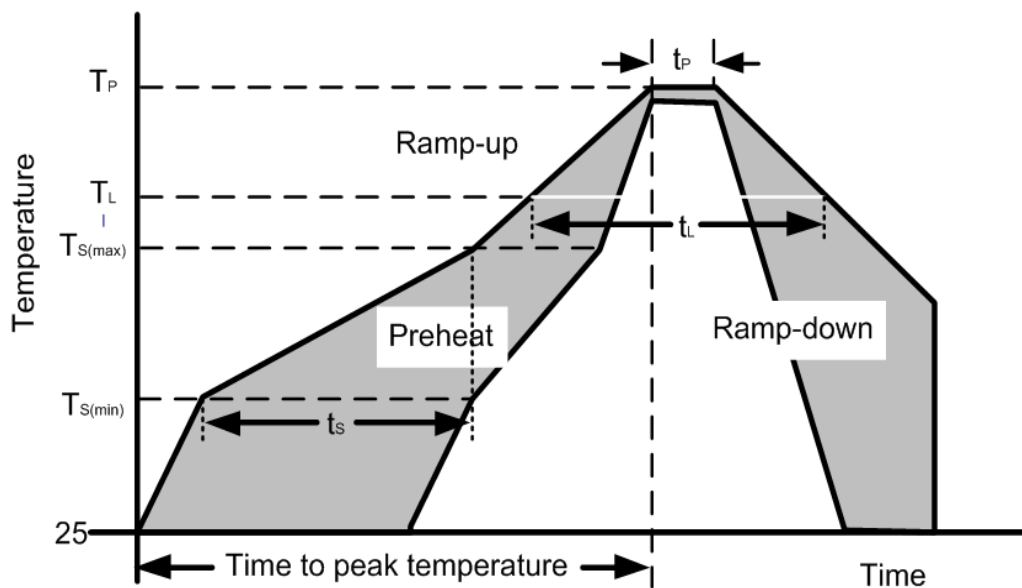


Figure 6: TLP Negative I-V Curve



**Soldering Parameters**

Reflow Condition		Pb – Free assembly
Pre Heat	Temperature Min ( $T_{S(min)}$ )	150°C
	Temperature Max ( $T_{S(max)}$ )	200°C
	Time (min to max) ( $t_s$ )	60 – 190 secs
Average ramp up rate (Liquidus Temp) ( $T_L$ ) to peak		5°C/second max
$T_{S(max)}$ to $T_L$ —Ramp-up Rate		5°C/second max
Reflow	Temperature ( $T_L$ ) (Liquidus)	217°C
	Temperature ( $t_L$ )	60 – 150 seconds
Peak Temperature ( $T_P$ )		260+0/-5 °C
Time within actual peak Temperature ( $t_p$ )		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature ( $T_P$ )		8 minutes Max.
Do not exceed		280°C



Outline Drawing –DFN0603-2L

### PACKAGE OUTLINE

TOP VIEW

BOTTOM VIEW

SIDE VIEW

DFN0603-2L

SYMBOL	MILIMETER	
	MIN	MAX
A	0.28	0.32
A1	0.00	0.05
b1	0.13	0.23
b2	0.14	0.24
c	0.05	0.15
D	0.55	0.65
e	0.350BSC	
L1	0.030BSC	
L2	0.025BSC	
L3	0.035BSC	
E	0.25	0.35
L	0.20	0.30
h	0.00	0.10

### Land Pattern

### Marking Codes

Part Number	WE03DS-B	Marking Code	<p>B = Specific Device Code M = Month Code</p>
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### Package Information

Qty: 15k/Reel

### CONTACT INFORMATION

**CYG WAYON CIRCUIT PROTECTION CO., LTD.**

No.1001, Shiwan(7) Road, Pudong District, Shanghai, P.R.China.201202

Tel: 86-21-68969993 Fax: 86-21-50757680 Email: [market@way-on.com](mailto:market@way-on.com)

WAYON website: <http://www.way-on.com>

For additional information, please contact your local Sales Representative.

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Specifications are subject to change without notice.  
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.  
Users should verify actual device performance in their specific applications.